



APT13005D

450V NPN HIGH VOLTAGE POWER TRANSISTOR

Features

- BV_{CEO} > 450V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 4A High Collector Current
- Integrated Anti-Parallel Diode to act as free-wheeling diode
- Anti-Saturation feature
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

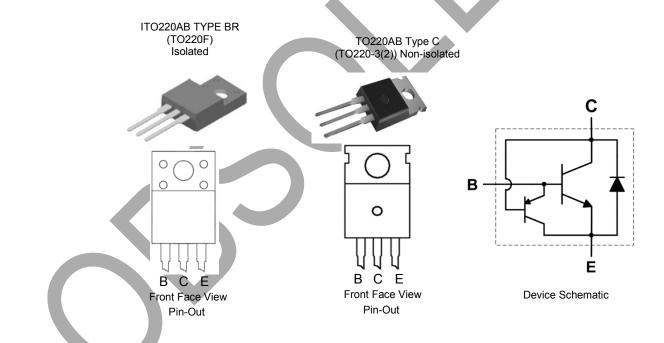
Applications

Low power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

Mechanical Data

- Case: ITO220AB TYPE BR (TO220F), TO220AB Type C
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Finish Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: ITO220AB TYPE BR (TO220F): 1500mg (Approximate)
 TO220AB Type C: 2000mg (Approximate)



Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13005DTF-G1	ITO220AB TYPE BR (TO220F)	APT13005DTF-G1	1,000 per Box in Tubes
APT13005DT-G1	TO220AB Type C (TO220-3(2))	APT13005DT-G1	1,000 per Box in Tubes

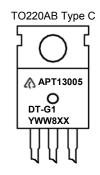
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information





A = Manufacturers' code marking For ITO220AB TYPE BR (TO220F), APT13005DTF-G1 = Product Type Marking ID For TO220AB Type C, APT13005DT-G1 = Product Type Marking ID YWW = Date Code Marking e.g. 312 = Year 2013, Week 12.

8 = Assembly site code XX = Batch Number

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CES}	700	V
Collector-Emitter Voltage	V_{CEO}	450	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current	Ic	4	Α
Peak Collector Current	I _{CM}	8	Α
Base Current	I _B	2	Α
Peak Base Current	I _{BM}	4	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Charac	eteristic	Symbol	Value	Unit
Power Dissipation @T _C = +25°C	For ITO220AB TYPE BR (TO220F)	P _D	28	W
, 3	For TO220AB Type C		75	
Thermal Resistance, Junction to Case	For ITO220AB TYPE BR (TO220F)	R _{eJC}	4.5	°C/W
	For TO220AB Type C		1.67	
Operating and Storage Temperature Rar	$T_{J,}T_{STG}$	-65 to +150	°C	

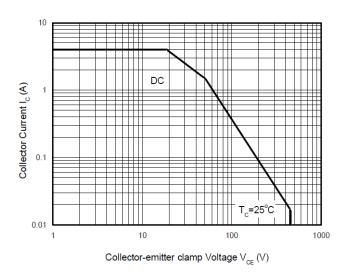
ESD Ratings (Note 5)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Safe Operating Areas (@T_A = +25°C, unless otherwise specified.)



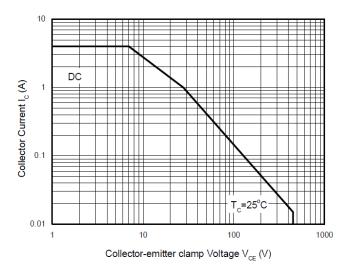
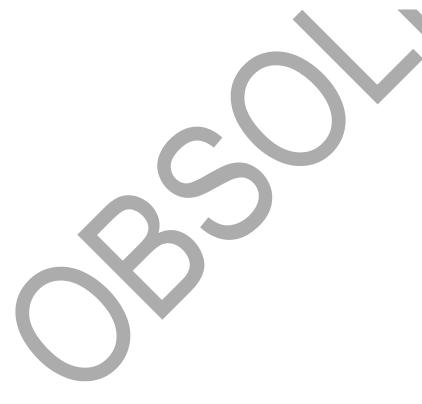


Figure 4. Safe Operating Areas TO220AB Type C

Figure 5. Safe Operating Areas ITO220AB Type BR (TO220F)

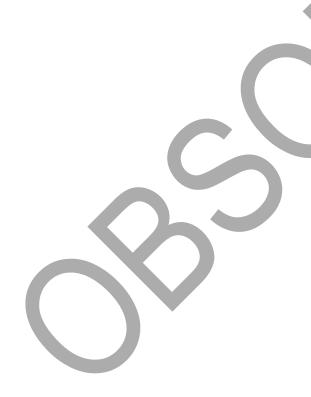




Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

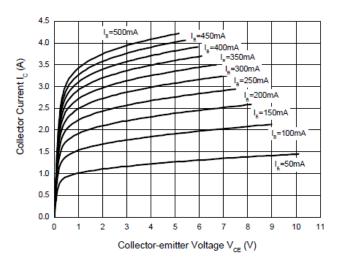
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	_	_	V	$I_C = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	450	_	_	V	$I_{C} = 100 \mu A$
Emitter-Base Breakdown Voltage	BV_{EBO}	9	_	_	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	1	1	10	μΑ	V _{CE} = 700V, V _{BE} = -1.5V
DC current transfer Static ratio (Note 6)	h _{FE}	15 8		35 35	1 1	$I_C = 1A, V_{CE} = 5V$ $I_C = 2A, V_{CE} = 5V$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}			0.3 0.6 0.9	V	$I_C = 1A$, $I_B = 0.2A$ $I_C = 2A$, $I_B = 0.5A$ $I_C = 4A$, $I_B = 1A$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}			1.1 1.3	>	$I_C = 1A$, $I_B = 0.2A$ $I_C = 2A$, $I_B = 0.5A$
Output Capacitance	C _{obo}	_	45	_/	ρF	V _{CB} = 10V, f = 0.1MHz
Transition Frequency	f _T	4	_		MHz	I _C = 0.5A, V _{CE} = 10V
Turn-on Time with Resistive Load	ton	_	_	0.7		
Storage Time with Resistive Load	ts	_	-/	4.0	μs	$I_C = 2A$, $V_{CC} = 125V$ $I_{B1} = -I_{B2} = 0.4A$
Fall Time with Resistive Load	t _f			0.8		1B11B2 - U.4A

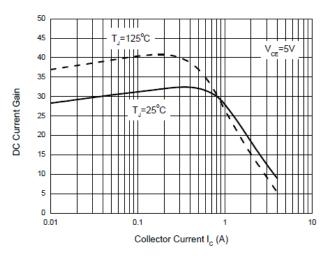
Note: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

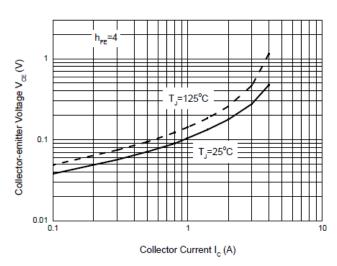


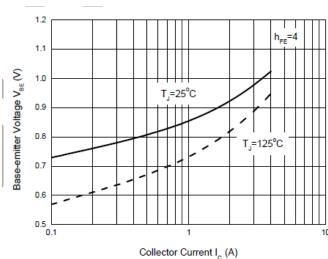


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)









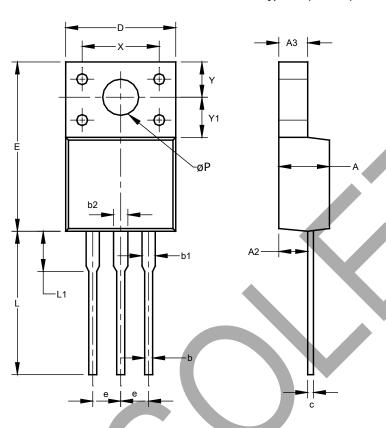




Package Outline Dimensions

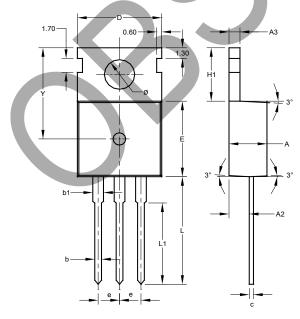
Please see http://www.diodes.com/package-outlines.html for the latest version.

ITO220AB Type BR (TO220F)



ITO220AB Type BR						
(TO220F)						
Dim	Min	Max	Тур			
A	4.300	4.900				
A2	2.520	2.920	-			
A3	2.350	2.900	ı			
b	0.550	0.900	ı			
b1	1.000	1.400	•			
b2	1.100	1.500	•			
C	0.450	0.600	•			
D	9.70	10.30				
E	14.70	16.00	-			
е	-	-	2.54			
L	12.50	13.50	-			
L1	2.790	4.500	1			
Х	6.90	7.10	-			
Υ	3.000	3.400	-			
Y1	3.370	3.900	-			
øΡ	3.000	3.550	-			
All Dimensions in mm						

TO220AB Type C



TO220AB Type C					
Dim	Min	Тур			
Α	-	-	4.500		
A2	-	-	2.400		
A3	-	-	1.300		
b	0.700	0.900	-		
b1	-	-	1.270		
С	0.400	0.600	-		
D	9.800	10.200			
Е	9.000	9.400	-		
е	-	-	2.54		
H1	6.300	6.700	-		
L	12.600	13.600	-		
L1	9.600	10.600	-		
Υ	-	-	11.100		
Ø	3.560	3.640	-		
All Dimensions in mm					

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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